

RELIABILITY REPORT
FOR
MAX14836GTG+T
PLASTIC ENCAPSULATED DEVICES

November 12, 2014

MAXIM INTEGRATED

160 RIO ROBLES
SAN JOSE, CA 95134

Approved by
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Conclusion

The MAX14836GTG+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX14836 transceiver is suitable for 24V binary sensors. Additional 24V digital inputs and outputs are provided. Two internal linear regulators generate common sensor power requirements: 5V and 3.3V. On-board DIO and DO drivers are independently configurable for push-pull, high-side (pnp), or low-side (npn) operation. The device detects a wake-up condition and generates a wake-up signal on the active-low WU output. An SPI interface allows configuration and monitoring of the devices. Extensive alarm conditions are detected and communicated through the active-low IRQ output and the SPI interface. The device features reverse-polarity, short-circuit, and thermal protection. All power lines are monitored for undervoltage conditions. Both DIO and DO drivers are specified for sinking/sourcing 200mA. The MAX14836 is available in a 4mm x 4mm, 24-pin TQFN package, and is specified over the -40°C to +105°C temperature range.

II. Manufacturing Information

A. Description/Function:	24V Dual-Output Sensor Transceiver
B. Process:	S45
C. Number of Device Transistors:	15024
D. Fabrication Location:	USA
E. Assembly Location:	Taiwan, China, Thailand
F. Date of Initial Production:	October 29, 2014

III. Packaging Information

A. Package Type:	24-pin TQFN 4x4
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-5500
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	48°C/W
K. Single Layer Theta Jc:	3°C/W
L. Multi Layer Theta Ja:	36°C/W
M. Multi Layer Theta Jc:	3°C/W

IV. Die Information

A. Dimensions:	100 X 100 mils
B. Passivation:	Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
F. Minimum Metal Spacing:	Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)
G. Bondpad Dimensions:	
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- | | |
|-----------------------------------|---|
| A. Quality Assurance Contacts: | Don Lipps (Manager, Reliability Engineering)
Bryan Preeshl (Vice President of QA) |
| B. Outgoing Inspection Level: | 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% for all Visual Defects. |
| C. Observed Outgoing Defect Rate: | < 50 ppm |
| D. Sampling Plan: | Mil-Std-105D |

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 96 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 11.5 \times 10^{-9}$$

$$\lambda = 11.5 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maximintegrated.com/qa/reliability/monitor>. Cumulative monitor data for the S45 Process results in a FIT Rate of 0.04 @ 25°C and 0.69 @ 55°C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot TARD4A015B, D/C 1404)

The RU93-0 die type has been found to have all pins able to withstand an HBM transient pulse of +/-1500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-100mA and overvoltage per JEDEC JESD78.

Table 1
Reliability Evaluation Test Results

MAX14836GTG+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (Note 1)	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	96	0	

Note 1: Life Test Data may represent plastic DIP qualification lots.